Green Products

10SQ050 SCHOTTKY BARRIER RECTIFIER

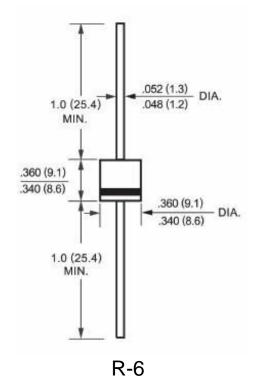
Applications:

- DC-DC converters
- AC adapter
- High frequency rectification circuit
- Bypass diodes

Features:

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches/ mm





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Marking Diagram:



Where XXXXX is YYWWL

10 = Forward Current (10A)

S = Package Type Q = Device Type

050 = Reverse Voltage (50V)

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
10SQ050	R-6 (Pb-Free)	500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	50	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _L = 75°C, rectangular wave form	10	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	Surge applied at rated load conditions half sine wave, 8.3ms	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 10 A, Pulse, T _J = 25 °C	0.55	V
	V _{F2}	@ 10 A, Pulse, T _J = 125 °C	0.50	V
Max. Reverse Current	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	30.0	mA

Thermal-Mechanical Specifications:

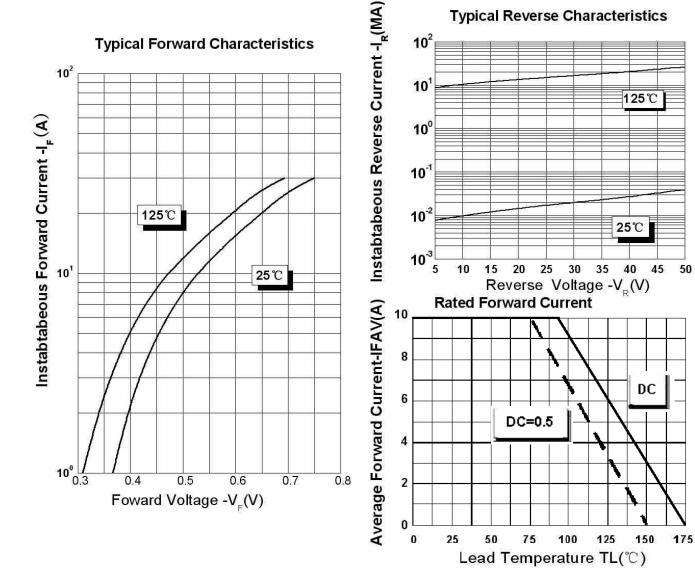
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature -1	T_J	_	-55 to +150	°C
Junction Temperature -2*	IJ	-	-55 to +175	C
Storage Temperature Range	T_{stg}	-	-55 to +175	°C
Maximum Thermal Resistance, Case to Heat Sink	$R_{ hetaJA}$	-	18	°C/W
Maximum Thermal Resistance, Junction to lead	$R_{ ext{ hetaJL}}$	-	8	°C/W
Case Style		R-6		

^{*} This rating is limited to the use for bypass diodes and the condition where the reverse bias voltage is not applied.

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